LM146/LM246/LM346 Programmable Quad Operational Amplifiers

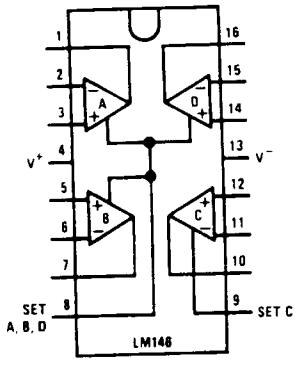
General Description

The LM146 series of quad op amps consists of four independent, high gain, internally compensated, low power, programmable amplifiers. Two external resistors (R_{SET}) allow the user to program the gain bandwidth product, slew rate, supply current, input bias current, input offset current and input noise. For example, the user can trade-off supply current for bandwidth or optimize noise figure for a given source resistance. In a similar way, other amplifier characteristics can be tailored to the application. Except for the two programming pins at the end of the package, the LM146 pin-out is the same as the LM124 and LM148.

Features ($I_{SET} = 10\ \mu A$)

- Programmable electrical characteristics
- Battery-powered operation
- Low supply current — 350 μA amplifier
- Guaranteed gain bandwidth product — 0.8 MHz min
- Large DC voltage gain — 120 dB
- Low noise voltage — 28 nV/√Hz
- Wide power supply range — ±1.5V to ±22V
- Class AB output stage—no crossover distortion
- Ideal pin out for Biquad active filters
- Input bias currents are temperature compensated

Connection Diagram (Dual-In-Line Package, Top View)



TL/H/5654–1

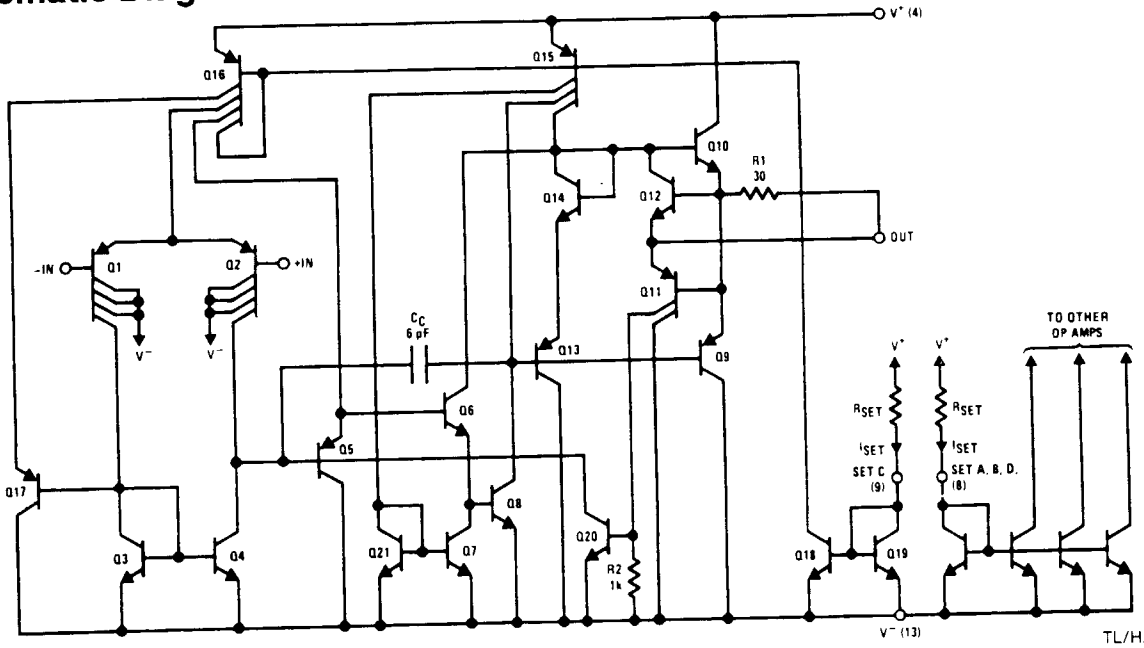
Order Number LM146J, LM246J, LM346J, LM346M or LM346N
See NS Package Number J16A, M16A or N16A

PROGRAMMING EQUATIONS

Total Supply Current = 1.4 mA (I_{SET}/10 μA)
Gain Bandwidth Product = 1 MHz (I_{SET}/10 μA)
Slew Rate = 0.4/μs (I_{SET}/10 μA)
Input Bias Current ≅ 50 nA (I_{SET}/10 μA)
I_{SET} = Current into pin 8, pin 9 (see schematic-diagram)

$$I_{SET} = \frac{V^+ - V^- - 0.6V}{R_{SET}}$$

Schematic Diagram



TL/H/5654–2

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/Distributors for availability and specifications.
(Note 5)

	LM146	LM246	LM346
Supply Voltage	±22V	±18V	±18V
Differential Input Voltage (Note 1)	±30V	±30V	±30V
CM Input Voltage (Note 1)	±15V	±15V	±15V
Power Dissipation (Note 2)	900 mW	500 mW	500 mW
Output Short-Circuit Duration (Note 3)	Indefinite	Indefinite	Indefinite
Operating Temperature Range	−55°C to +125°C	−25°C to +85°C	0°C to +70°C
Maximum Junction Temperature	150°C	110°C	100°C
Storage Temperature Range	−65°C to +150°C	−65°C to +150°C	−65°C to +150°C
Lead Temperature (Soldering, 10 seconds)	260°C	260°C	260°C
Thermal Resistance (θ_{jA}), (Note 2)			
Cavity DIP (J) Pd	900 mW	900 mW	900 mW
θ_{jA}	100°C/W	100°C/W	100°C/W
Small Outline (M) θ_{jA}			115°C/W
Molded DIP (N) Pd			500 mW
θ_{jA}			90°C/W
Soldering Information			
Dual-In-Line Package			
Soldering (10 seconds)	+260°C	+260°C	+260°C
Small Outline Package			
Vapor Phase (60 seconds)	+215°C	+215°C	+215°C
Infrared (15 seconds)	+220°C	+220°C	+220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

ESD rating is to be determined.

DC Electrical Characteristics ($V_S = \pm 15V$, $I_{SET} = 10\ \mu A$, Note 4)

Parameter	Conditions	LM146			LM246/LM346			Units
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage	$V_{CM} = 0V$, $R_S \leq 50\Omega$, $T_A = 25°C$		0.5	5		0.5	6	mV
Input Offset Current	$V_{CM} = 0V$, $T_A = 25°C$		2	20		2	100	nA
Input Bias Current	$V_{CM} = 0V$, $T_A = 25°C$		50	100		50	250	nA
Supply Current (4 Op Amps)	$T_A = 25°C$		1.4	2.0		1.4	2.5	mA
Large Signal Voltage Gain	$R_L = 10\ k\Omega$, $\Delta V_{OUT} = \pm 10V$, $T_A = 25°C$	100	1000		50	1000		V/mV
Input CM Range	$T_A = 25°C$	±13.5	±14		±13.5	±14		V
CM Rejection Ratio	$R_S \leq 10\ k\Omega$, $T_A = 25°C$	80	100		70	100		dB
Power Supply Rejection Ratio	$R_S \leq 10\ k\Omega$, $T_A = 25°C$	80	100		74	100		dB
Output Voltage Swing	$R_L \geq 10\ k\Omega$, $T_A = 25°C$	±12	±14		±12	±14		V
Short-Circuit	$T_A = 25°C$	5	20	35	5	20	35	mA
Gain Bandwidth Product	$T_A = 25°C$	0.8	1.2		0.5	1.2		MHz
Phase Margin	$T_A = 25°C$		60			60		Deg
Slew Rate	$T_A = 25°C$		0.4			0.4		V/μs
Input Noise Voltage	$f = 1$ kHz, $T_A = 25°C$		28			28		nV/√Hz
Channel Separation	$R_L = 10\ k\Omega$, $\Delta V_{OUT} = 0V$ to $\pm 12V$, $T_A = 25°C$		120			120		dB
Input Resistance	$T_A = 25°C$		1.0			1.0		MΩ
Input Capacitance	$T_A = 25°C$		2.0			2.0		pF
Input Offset Voltage	$V_{CM} = 0V$, $R_S \leq 50\Omega$		0.5	6		0.5	7.5	mV
Input Offset Current	$V_{CM} = 0V$		2	25		2	100	nA
Input Bias Current	$V_{CM} = 0V$		50	100		50	250	nA
Supply Current (4 Op Amps)			1.7	2.2		1.7	2.5	mA
Large Signal Voltage Gain	$R_L = 10\ k\Omega$, $\Delta V_{OUT} = \pm 10V$	50	1000		25	1000		V/mV

DC Electrical Characteristics (Continued) ($V_S = \pm 15V$, $I_{SET} = 1\ \mu A$)

Parameter	Conditions	LM146			LM246/LM346			Units
		Min	Typ	Max	Min	Typ	Max	
Input CM Range		±13.5	±14		±13.5	±14		V
CM Rejection Ratio	$R_S \leq 50\Omega$	70	100		70	100		dB
Power Supply Rejection Ratio	$R_S \leq 50\Omega$	76	100		74	100		dB
Output Voltage Swing	$R_L \geq 10\ k\Omega$	±12	±14		±12	±14		V
Input Offset Voltage	$V_{CM} = 0V$, $R_S \leq 50\Omega$, $T_A = 25°C$		0.5	5		0.5	7	mV
Input Bias Current	$V_{CM} = 0V$, $T_A = 25°C$		7.5	20		7.5	100	nA
Supply Current (4 Op Amps)	$T_A = 25°C$		140	250		140	300	μA
Gain Bandwidth Product	$T_A = 25°C$	80	100		50	100		kHz

DC Electrical Characteristics ($V_S = \pm 1.5V$, $I_{SET} = 10\ \mu A$)

Parameter	Conditions	LM146			LM246/LM346			Units
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage	$V_{CM} = 0V$, $R_S \leq 50\Omega$, $T_A = 25°C$		0.5	5		0.5	7	mV
Input CM Range	$T_A = 25°C$	±0.7			±0.7			V
CM Rejection Ratio	$R_S \leq 50\Omega$, $T_A = 25°C$		80			80		dB
Output Voltage Swing	$R_L \geq 10\ k\Omega$, $T_A = 25°C$	±0.6			±0.6			V

Note 1: For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

Note 2: The maximum power dissipation for these devices must be derated at elevated temperatures and is dictated by T_{jMAX}, θ_{jA}, and the ambient temperature, T_A. The maximum available power dissipation at any temperature is $P_d = (T_{jMAX} - T_A)/\theta_{jA}$ or the 25°C P_{dMAX}, whichever is less.

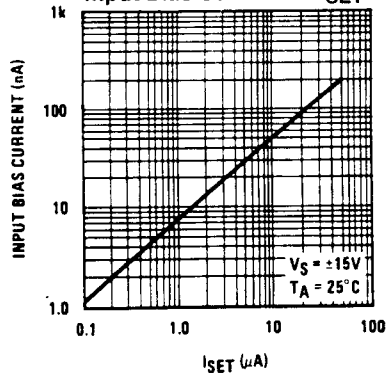
Note 3: Any of the amplifier outputs can be shorted to ground indefinitely; however, more than one should not be simultaneously shorted as the maximum junction temperature will be exceeded.

Note 4: These specifications apply over the absolute maximum operating temperature range unless otherwise noted.

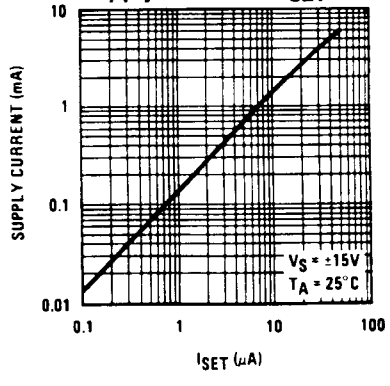
Note 5: Refer to RETS146X for LM146J military specifications.

Typical Performance Characteristics

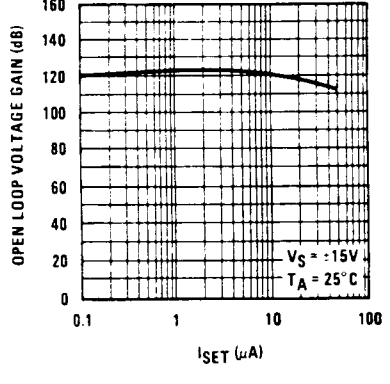
Input Bias Current vs I_{SET}



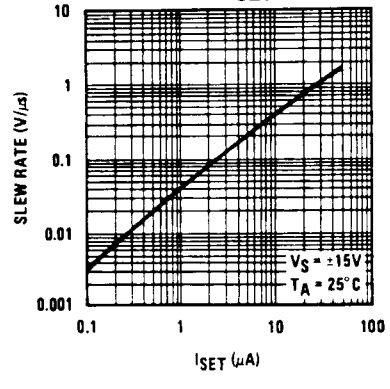
Supply Current vs I_{SET}



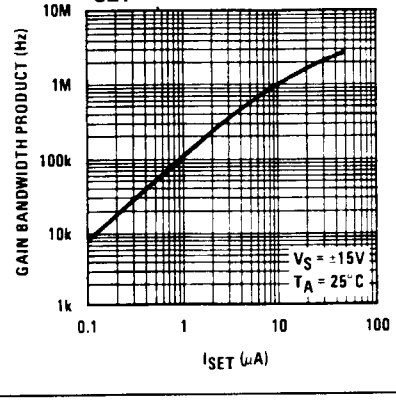
Open Loop Voltage Gain vs I_{SET}



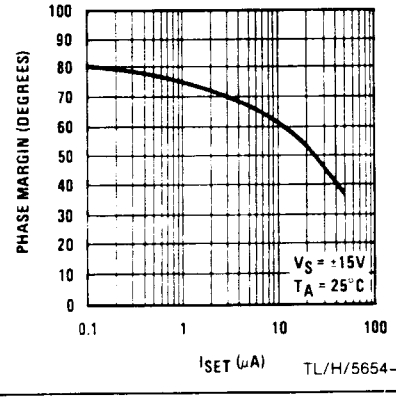
Slew Rate vs I_{SET}



Gain Bandwidth Product vs I_{SET}



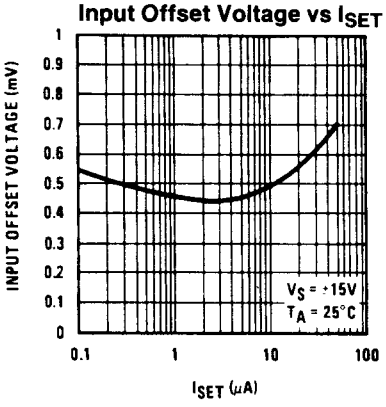
Phase Margin vs I_{SET}



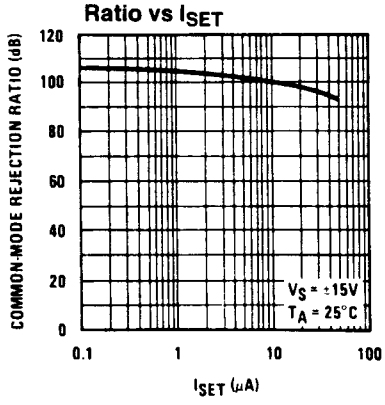
TL/H/5654–3

Typical Performance Characteristics (Continued)

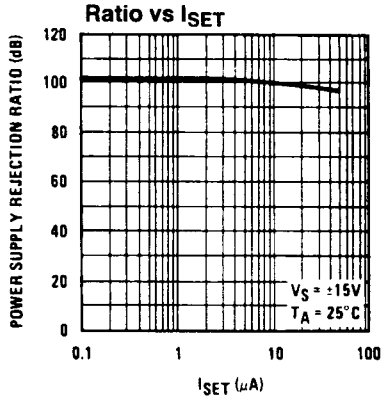
Input Offset Voltage vs I_{SET}



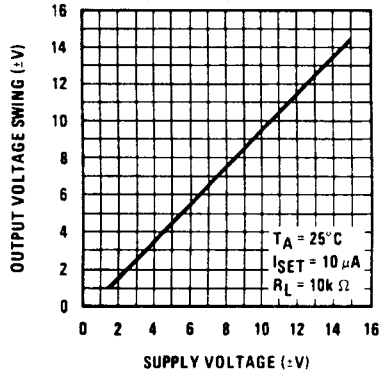
Common-Mode Rejection Ratio vs I_{SET}



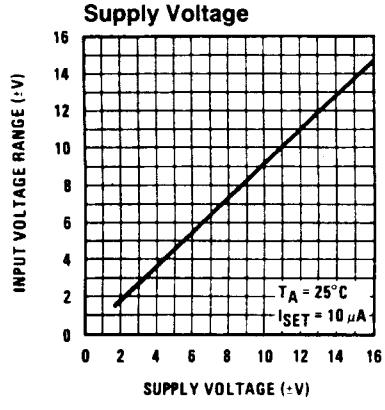
Power Supply Rejection Ratio vs I_{SET}



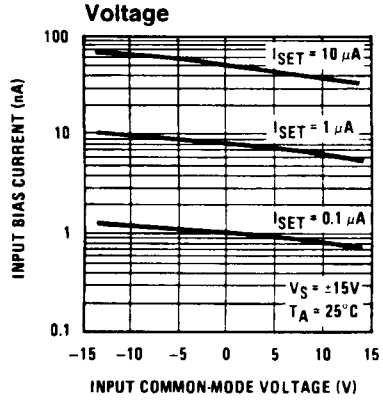
Output Voltage Swing vs Supply Voltage



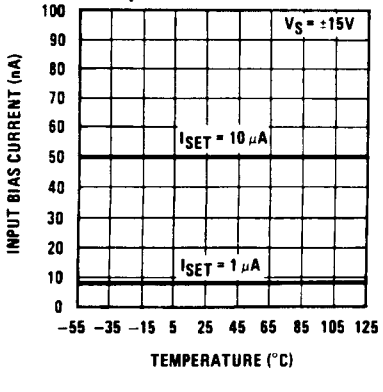
Input Voltage Range vs Supply Voltage



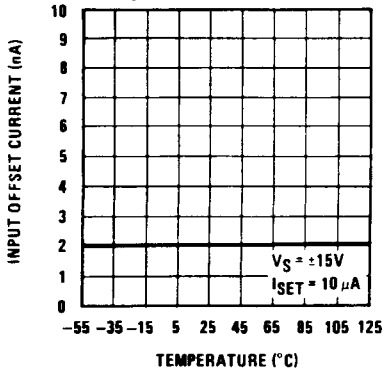
Input Bias Current vs Input Common-Mode Voltage



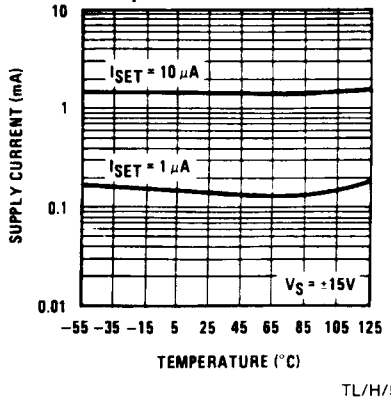
Input Bias Current vs Temperature



Input Offset Current vs Temperature



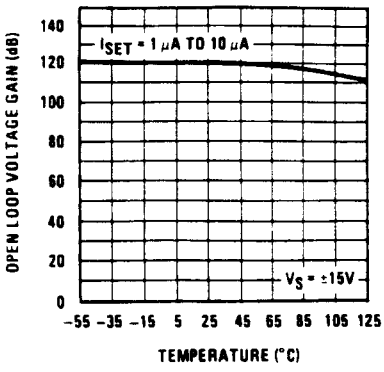
Supply Current vs Temperature



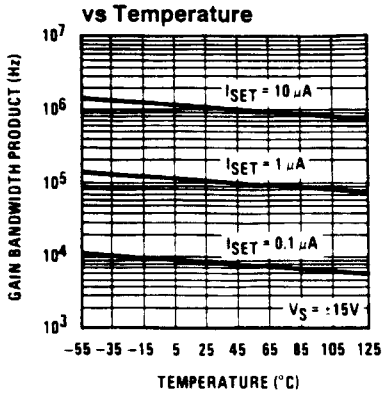
TL/H/5654–4

Typical Performance Characteristics (Continued)

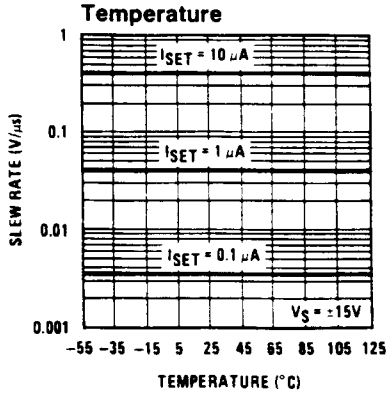
Open Loop Voltage Gain vs Temperature



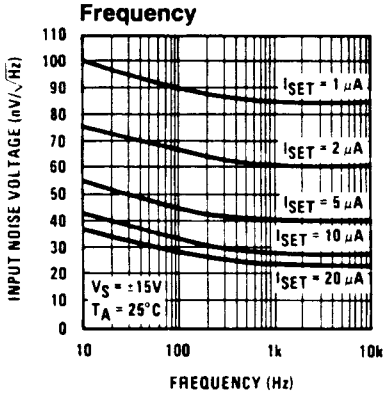
Gain Bandwidth Product vs Temperature



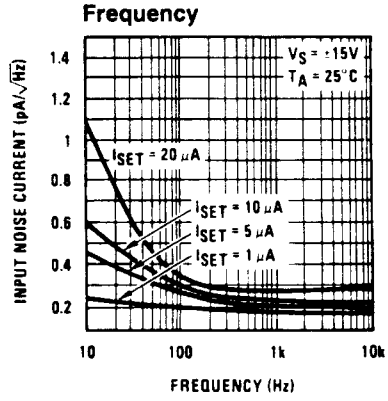
Slew Rate vs Temperature



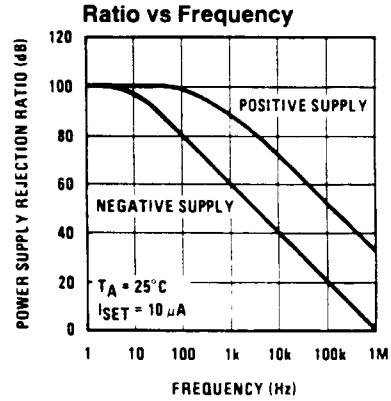
Input Noise Voltage vs Frequency



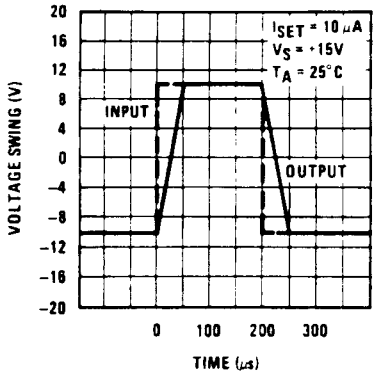
Input Noise Current vs Frequency



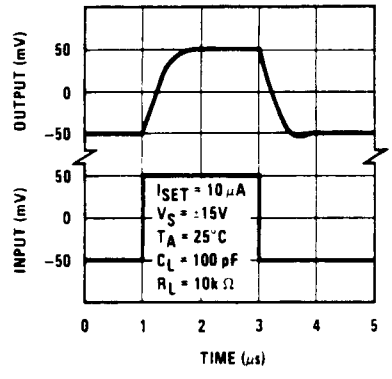
Power Supply Rejection Ratio vs Frequency



Voltage Follower Pulse Response

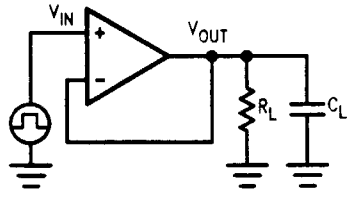


Voltage Follower Transient Response



TL/H/5654–5

Transient Response Test Circuit



TL/H/5654–6